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RoHS 2002/95/EC

NTE3033
Infrared Photodiode

Description:
The NTE3033 is a high output, high speed silicon photodiode mounted in a side–viewing plastic package with visible light cutoff filter.

Features:
- Visible Ray Cutoff Mold Type
- High Output Power
- High Speed Response

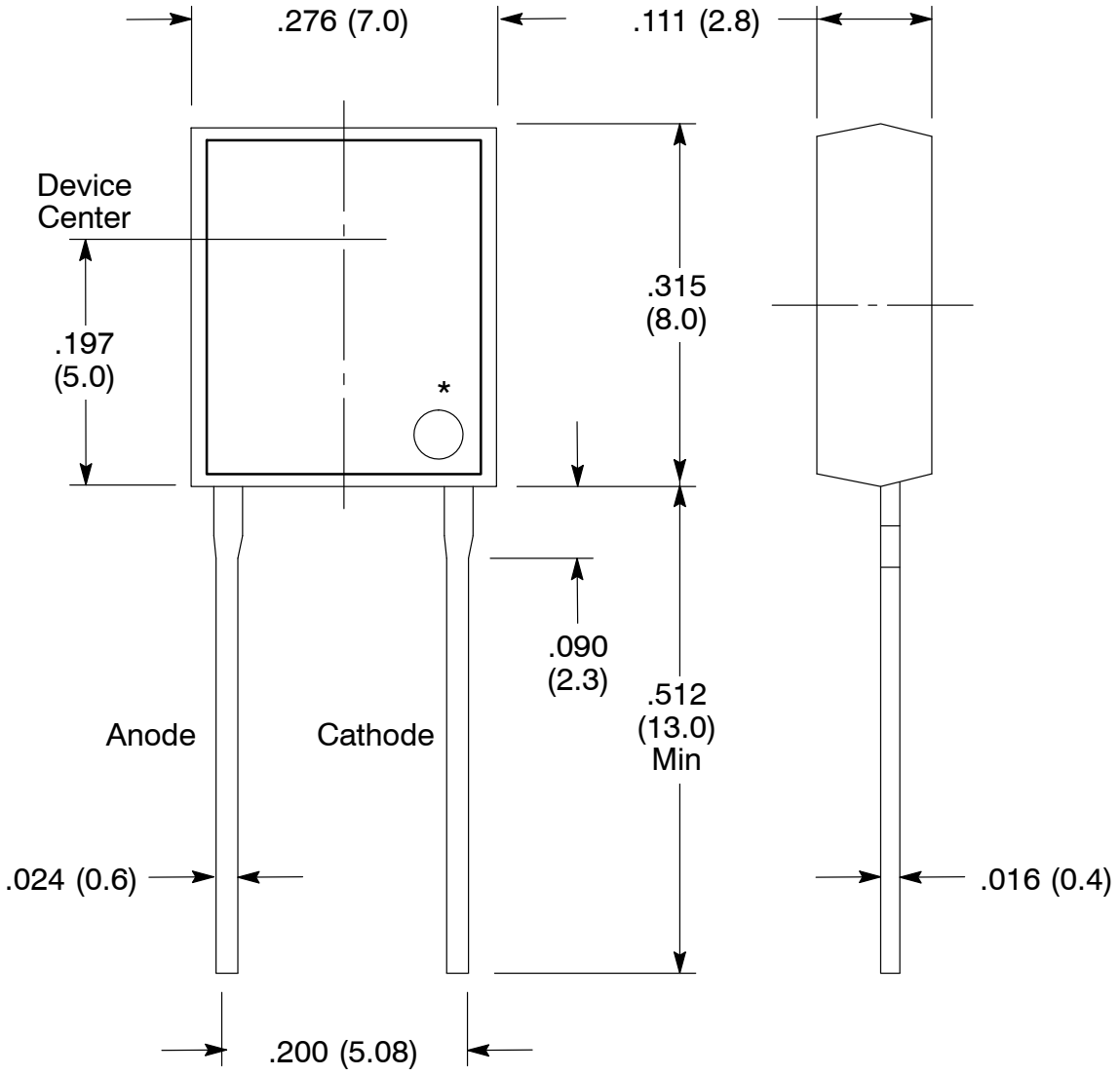
Applications:
- Optical Transmission
- Optic Receiver Modules

Absolute Maximum Ratings: (T_A = +25°C unless otherwise specified)
Reverse Voltage, V_R 35V
Power Dissipation, P_D 150mW
Operating Temperature Range, T_{opr} . . . . . –30° to +70°C
Storage Temperature Range, T_{stg} . . . . . –40° to +80°C
Lead Temperature (During Soldering, 2mm from the package, 5sec Max.), T_L . . . . . +260°C

Electro–Optical Characteristics: (T_A = +25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Open Circuit Voltage	V_{CC}	E_V = 1000 1x, Note 1	–	0.38	–	V
Short Circuit Current	I_{SC}	E_V = 1000 1x, Note 1	24	50	–	μA
Curve Factor	CF		0.55	–	–	–
Dark Current	I_D	V_R = 10V	–	–	30	nA
Capacitance	C_t	V = 0V, f = 1MHz	–	49	–	pF
Temperature Coefficient of V_{OC}	αt		–	–2.2	–	mV/°C
Temperature Coefficient of I_{SC}	βt		–	0.18	–	%/°C
Spectral Sensitivity	λ		700 1050			nm
Peak Emission Wavelength	λ_P		–	940	–	nm
Half Angle	$\Delta\Theta$		–	±70	–	deg

Note 1. Source: Tungsten filament lamp 2856°K



* Denotes Cathode mark